## 64M-BIT MASK-PROGRAMMABLE ROM 8M-WORD BY 8-BIT (BYTE MODE) / 4M-WORD BY 16-BIT (WORD MODE)

## Description

The $\mu \mathrm{PD} 23 \mathrm{C} 64300$ is a $67,108,864$ bits mask-programmable ROM. The word organization is selectable (BYTE mode :
$8,388,608$ words by 8 bits, WORD mode : $4,194,304$ words by 16 bits).
The active levels of OE (Output Enable Input) can be selected with mask-option.
The $\mu \mathrm{PD} 23 \mathrm{C} 64300$ is packed in 48-pin TAPE FBGA.

## Features

- Pin compatible with NOR Flash Memory
- Word organization
$8,388,608$ words by 8 bits (BYTE mode)
4,194,304 words by 16 bits (WORD mode)
- Operating supply voltage : Vcc $=2.7 \mathrm{~V}$ to 3.6 V

| Operating supply voltage <br> Vcc | Access time <br> $\mathrm{ns}(\mathrm{MAX})$. | Power supply current (Active mode) <br> $\mathrm{mA}(M A X)$. | Standby current (CMOS level input) |
| :---: | :---: | :---: | :---: |
| $3.0 \mathrm{~V} \pm 0.3 \mathrm{~V}$ (MAX.) |  |  |  |

## Ordering Information

| Part Number | Package |
| :---: | :---: |
| $\mu$ PD23C64300F9-xxx-BC3 | 48-pin TAPE FBGA $(8 \times 6)$ |

(xxx : ROM code suffix No.)

## Marking Image

| Part Number | Marking ( $\square$ ) |
| :---: | :---: |
| $\mu$ PD23C64300F9-xxx-BC3 | A |



## Pin Configuration

/xxx indicates active low signal.

## 48-pin TAPE FBGA (8 x 6)



|  | A | B | C | D | E | F | G | H |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 6 | A13 | A12 | A14 | A15 | A16 | WORD, <br> /BYTE | O15, <br> A-1 | GND |
| 5 | A9 | A8 | A10 | A11 | O7 | O14 | O13 | O6 |
| 4 | NC | NC | A21 | A19 | O5 | O12 | $V_{c c}$ | O4 |
| 3 | NC | NC | A18 | A20 | O2 | O10 | O11 | O3 |
| 2 | A7 | A17 | A6 | A5 | O0 | O8 | O9 | O1 |
| 1 | A3 | A4 | A2 | A1 | A0 | ICE | IOE or | GND |
|  |  |  |  |  |  |  | OE |  |


|  | H | G | F | E | D | C | B | A |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 6 | GND | O15, <br> A-1 | WORD, <br> /BYTE | A16 | A15 | A14 | A12 | A13 |
| 5 | O6 | O13 | O14 | O7 | A11 | A10 | A8 | A9 |
| 4 | O4 | Vcc $^{\text {C }}$ | O12 | O5 | A19 | A21 | NC | NC |
| 3 | O3 | O11 | O10 | O2 | A20 | A18 | NC | NC |
| 2 | O1 | O9 | O8 | O0 | A5 | A6 | A17 | A7 |
| 1 | GND | IOE or | ICE | A0 | A1 | A2 | A4 | A3 |


| A0 to A21 | : Address inputs |
| :--- | :--- |
| O0 to O7, O8 to O14 : | Data outputs |
| O15, A-1 | : Data output 15 (WORD mode), |
|  | LSB Address input (BYTE mode) |
| WORD, /BYTE | : Mode select |
| /CE | : Chip Enable |
| /OE or OE | : Output Enable |
| Vcc | : Supply voltage |
| GND | : Ground |
| NCNote | : No Connection |
| DC | $:$ Don't Care |

Note Some signals can be applied because this pin is not connected to the inside of the chip.

Remark Refer to Package Drawing for the index mark.

## Input / Output Pin Functions

| Pin name | Input / Output | Function |
| :---: | :---: | :---: |
| WORD, /BYTE | Input | The pin for switching WORD mode and BYTE mode. <br> High level : WORD mode (4M-word by 16-bit) <br> Low level : BYTE mode (8M-word by 8-bit) |
| A0 to A21 <br> (Address inputs) | Input | Address input pins. <br> A0 to A21 are used differently in the WORD mode and the BYTE mode. <br> WORD mode (4M-word by 16-bit) <br> A0 to A21 are used as 22 bits address signals. <br> BYTE mode (8M-word by 8-bit) <br> A0 to A21 are used as the upper 22 bits of total 23 bits of address signal. <br> (The least significant bit ( $\mathrm{A}-1$ ) is combined to O 15 .) |
| O0 to O7, O8 to O14 (Data outputs) | Output | Data output pins. <br> O0 to O7, O8 to O14 are used differently in the WORD mode and the BYTE mode. <br> WORD mode (4M-word by 16-bit) <br> The lower 15 bits of 16 bits data outputs to O 0 to O 14 . <br> (The most significant bit (O15) combined to $\mathrm{A}-1$.) <br> BYTE mode (8M-word by 8-bit) <br> 8 bits data outputs to O 0 to O 7 and also O 8 to O 14 are high impedance. |
| O15, A-1 <br> (Data output 15, <br> LSB Address input) | Output, Input | O15, A-1 are used differently in the WORD mode and the BYTE mode. WORD mode (4M-word by 16-bit) <br> The most significant output data bus (O15). <br> BYTE mode (8M-word by 8-bit) <br> The least significant address bus (A-1). |
| /CE <br> (Chip Enable) | Input | Chip activating signal. <br> When the OE is active, output states are following. <br> High level : High-Z <br> Low level : Data out |
| /OE or OE or DC <br> (Output Enable, Don't care) | Input | Output enable signal. The active level of OE is mask option. The active level of OE can be selected from high active, low active and Don't care at order. |
| Vcc | - | Supply voltage |
| GND | - | Ground |
| NC | - | Not internally connected. (The signal can be connected.) |

## Block Diagram



## Mask Option

The active levels of output enable pin (/OE or OE or DC) are mask programmable and optional, and can be selected from among " 0" " 1 " " x " shown in the table below.

| Option | /OE or OE or DC | OE active level |
| :---: | :---: | :---: |
| 0 | IOE | L |
| 1 | OE | H |
| x | DC | Don't care |

Operation modes for each option are shown in the tables below.

Operation mode (Option : 0)

| /CE | IOE | Mode | Output state |
| :---: | :---: | :---: | :---: |
| L | L | Active | Data out |
|  | H |  | High-Z |
| H | H or L | Standby | High-Z |

Operation mode (Option : 1)

| ICE | OE | Mode | Output state |
| :---: | :---: | :---: | :---: |
| L | L | Active | High-Z |
|  | H |  | Data out |
|  | H | H or L | Standby |

Operation mode (Option : x)

| $/ C E$ | DC | Mode | Output state |
| :---: | :---: | :---: | :---: |
| L | H or L | Active | Data out |
| H | H or L | Standby | High-Z |

Remark L: Low level input
H : High level input

## Electrical Specifications

Absolute Maximum Ratings

| Parameter | Symbol | Condition | Rating | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Supply voltage | Vcc |  | -0.3 to +4.6 | V |
| Input voltage | $\mathrm{V}_{1}$ |  | -0.3 to $\mathrm{Vcc}+0.3$ | V |
| Output voltage | Vo |  | -0.3 to $\mathrm{Vcc}+0.3$ | V |
| Operating ambient temperature | $\mathrm{T}_{\mathrm{A}}$ |  | -10 to +70 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $\mathrm{T}_{\text {stg }}$ |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Caution Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

## Capacitance (TA $=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Test condition | MIN. | TYP. | MAX. | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Input capacitance | CI | $\mathrm{f}=1 \mathrm{MHz}$ |  |  | 10 | pF |
| Output capacitance | Co |  |  |  | 12 | pF |

DC Characteristics ( $\mathrm{TA}=\mathbf{- 1 0}$ to $\mathbf{+ 7 0}{ }^{\circ} \mathrm{C}, \mathrm{Vcc}=\mathbf{2 . 7}$ to $\mathbf{3 . 6} \mathrm{V}$ )

| Parameter | Symbol | Test conditions |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| High level input voltage | VIH |  |  | 2.0 |  | $\mathrm{Vcc}+0.3$ | V |
| Low level input voltage | VIL | $\mathrm{Vcc}=3.0 \mathrm{~V} \pm 0.3 \mathrm{~V}$ |  | -0.3 |  | +0.5 | V |
|  |  | $\mathrm{Vcc}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ |  | -0.3 |  | +0.8 |  |
| High level output voltage | Vor | $\mathrm{IOH}=-100 \mu \mathrm{~A}$ |  | 2.4 |  |  | V |
| Low level output voltage | Vol | $\mathrm{loL}=2.1 \mathrm{~mA}$ |  |  |  | 0.4 | V |
| Input leakage current | lı | $\mathrm{V}_{1}=0 \mathrm{~V}$ to Vcc |  | -10 |  | +10 | $\mu \mathrm{A}$ |
| Output leakage current | ILo | V o $=0 \mathrm{~V}$ to Vcc , Chip deselected |  | -10 |  | +10 | $\mu \mathrm{A}$ |
| Power supply current | Icc1 | $\begin{aligned} & / \mathrm{CE}=\mathrm{V}_{\mathrm{IL}}(\text { Active mode }), \\ & \mathrm{lo}=0 \mathrm{~mA} \end{aligned}$ | $\mathrm{Vcc}=3.0 \mathrm{~V} \pm 0.3 \mathrm{~V}$ |  |  | 40 | mA |
|  |  |  | $\mathrm{V}_{\mathrm{cc}}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ |  |  | 55 |  |
| Standby current | Icc3 | $/ \mathrm{CE}=\mathrm{Vcc}-0.2 \mathrm{~V}$ (Standby mode) |  |  |  | 30 | $\mu \mathrm{A}$ |

## AC Characteristics ( $\mathrm{TA}_{\mathrm{A}}=-10$ to $+70^{\circ} \mathrm{C}, \mathrm{Vcc}=2.7$ to 3.6 V )

| Parameter | Symbol | Test condition | $\mathrm{Vcc}=3.0 \mathrm{~V} \pm 0.3 \mathrm{~V}$ |  |  | $\mathrm{Vcc}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |  |
| Address access time | tacc |  |  |  | 100 |  |  | 90 | ns |
| Address skew time | tskew | Note |  |  | 10 |  |  | 10 | ns |
| Chip enable access time | tce |  |  |  | 100 |  |  | 90 | ns |
| Output enable access time | toe |  |  |  | 25 |  |  | 25 | ns |
| Output hold time | tor |  | 0 |  |  | 0 |  |  | ns |
| Output disable time | tbF |  | 0 |  | 25 | 0 |  | 25 | ns |
| WORD, /BYTE access time | twb |  |  |  | 100 |  |  | 90 | ns |

Note tskew indicates the following three types of time depending on the condition.

1) When switching /CE from high level to low level, tskEw is the time from the /CE low level input point until the next address is determined.
2) When switching /CE from low level to high level, tskew is the time from the address change start point to the /CE high level input point.
3) When /CE is fixed to low level, tskEw is the time from the address change start point until the next address is determined.

Since specs are defined for tskew only when /CE is active, tskEw is not subject to limitations when /CE is switched from high level to low level following address determination, or when the address is changed after /CE is switched from low level to high level.

Remark tDF is the time from inactivation of Chip Enable input (/CE) or Output Enable input (/OE or OE) to high impedance state output.

## AC Test Conditions

Input waveform (Rise/Fall time $\leq \mathbf{5 n s}$ )


## Output waveform



## Output load

$1 \mathrm{TTL}+100 \mathrm{pF}$

## Cautions on power application

To ensure normal operation, always apply power using /CE following the procedure shown below.

1) Input a high level to /CE during and after power application.
2) Hold the high level input to /CE for 200 ns or longer (wait time).
3) Start normal operation after the wait time has elapsed.

## Power Application Timing Chart 1 (When /CE is made high at power application)



## Power Application Timing Chart 2 (When /CE is made high after power application)



Caution Other signals can be either high or low during the wait time.

## Read Cycle Timing Chart



Notes 1. During WORD mode, $\mathrm{A}-1$ is O 15.
2. tDF is the time from inactivation of Chip Enable input (/CE) or Output Enable input (/OE or OE) to high impedance state output.
3. During BYTE mode, O 8 to O 14 are high impedance and O 15 is $\mathrm{A}-1$.

## WORD, IBYTE Switch Timing Chart



Remark Chip Enable (/CE) and Output Enable (/OE or OE) : Active.

## Package Drawing

## 48-PIN TAPE FBGA(8x6)



| ITEM | MILLIMETERS |
| :---: | :--- |
| D | $6.0 \pm 0.1$ |
| E | $8.0 \pm 0.1$ |
| w | 0.2 |
| e | 0.80 |
| A | $0.97 \pm 0.10$ |
| A 1 | $0.27 \pm 0.05$ |
| A2 | 0.70 |
| b | $0.45 \pm 0.05$ |
| x | 0.08 |
| y | 0.1 |
| y 1 | 0.2 |
| ZD | 1.00 |
| ZE | 1.20 |
|  | P48F9-80-BC3 |

## Recommended Soldering Conditions

Please consult with our sales offices for soldering conditions of the $\mu$ PD23C64300.

Type of Surface Mount Device
$\mu$ PD23C64300F9-BC3 $: 48$-pin TAPE FBGA $(8 \times 6)$

## Revision History

| Edition/ <br> Date | Page |  | Type of revision | Location | Description <br> (Previous edition $\rightarrow$ This edition) |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | This edition | Previous edition |  |  |  |
| 4th edition/ <br> Feb. 2004 | Throughout | Throughout | Deletion | Ordering Information | $\mu \mathrm{PD} 23 \mathrm{C} 64300 \mathrm{GZ}-\mathrm{xxx-MJH}$ |
|  |  |  |  | Package | 48-pin PLASTIC TSOP (I) <br> (12 x 20) (Normal bent) |

[MEMO]

## NOTES FOR CMOS DEVICES

(1) VOLTAGE APPLICATION WAVEFORM AT INPUT PIN

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between $\mathrm{V}_{\mathrm{IL}}$ (MAX) and $\mathrm{V}_{\mathrm{IH}}$ (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between VIL (MAX) and VIH (MIN).
(2) HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to Vod or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

## (3) PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.
(4) STATUS BEFORE INITIALIZATION

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

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